



**DUAL 20V N-CHANNEL ENHANCEMENT MODE MOSFET** 

## Product Summary

BV <sub>DSS</sub>	R <sub>ds(on)</sub>	Package	I <sub>D</sub> T <sub>A</sub> = +25°C (Notes 5 & 6)	
20V	$130m\Omega @ V_{GS} = 4.5V$	MSOP-8	2.5A	
200	150mΩ @ $V_{GS}$ = 2.7V	WISOF-0	2.3A	

#### Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### Applications

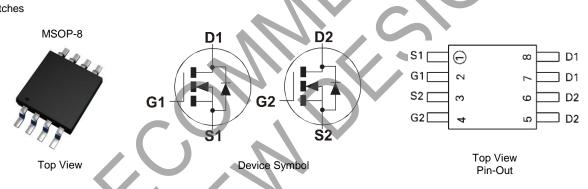
- DC-DC Converters
- Power Management Functions
- Motor Control
- Disconnect Switches

#### Features

- Low On-Resistance
- Low Threshold
- Fast Switching Speed
- Low Gate Drive
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: MSOP-8
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.0277 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXMD63N02XTA	ZXM63N02	7	12	1,000
ZXMD63N02XTC	ZXM63N02	13	12	4,000
Notes: 1. No purposely added	d lead. Fully EU Directive 2002/9	5/EC (RoHS), 2011/65/EU (RoHS	2) & 2015/863/EU (RoHS 3) com	pliant.

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

. See https://www.doddes.com/quality/lead-nee/ for more information about blodes incorporated's definitions of halogen- and Antimony-free, "Green" and Antimony-free, "Green" and <math>Antimony-free, "Green" and Antimony-free, "Green" and Antimony-free (21500 ppm) and (21500 ppm

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



ZXM63N02 = Product Type Marking Code



ZXMD63N02X

#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value        20        ±12	Unit V V	
Drain-Source Voltage						V <sub>DSS</sub>
Gate-Source Voltage			V <sub>GSS</sub>			
Continuous Drain Current	Steady State	$@V_{GS} = 10V; T_A = +2$ $@V_{GS} = 10V; T_A = +7$ $@V_{GS} = 10V; T_A = +7$	70°C (Notes 5 & 6)	ID	2.5 1.9 0.78	А
Pulsed Drain Current (Notes 6 & 7)			I <sub>DM</sub>	19	А	
Continuous Source Current (Body Diode)			(Notes 5 & 6)	ls	1.5	А
Pulsed Source Current (Body Diode)			(Notes 6 & 7)	I <sub>SM</sub>	19	А

#### Thermal Characteristics

Characteristic		Symbol	Value	Unit	
	(Notes 6 & 8)		0.87		
Power Dissipation	(Notes 5 & 6)	PD	1.25	W	
	(Notes 8 & 9)		1.04		
	(Notes 6 & 8)		143		
Thermal Resistance, Junction to Ambient	(Notes 5 & 6)	R <sub>0JA</sub>	100	°C/W	
	(Notes 8 & 9)		120	~	
Thermal Resistance, Junction to Leads	(Note 10)	R <sub>ejl</sub>	84.9	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	C°	

5. For a device surface mounted on FR-4 PCB measured at t  $\leq$  10 sec.

6. For device with one active die.

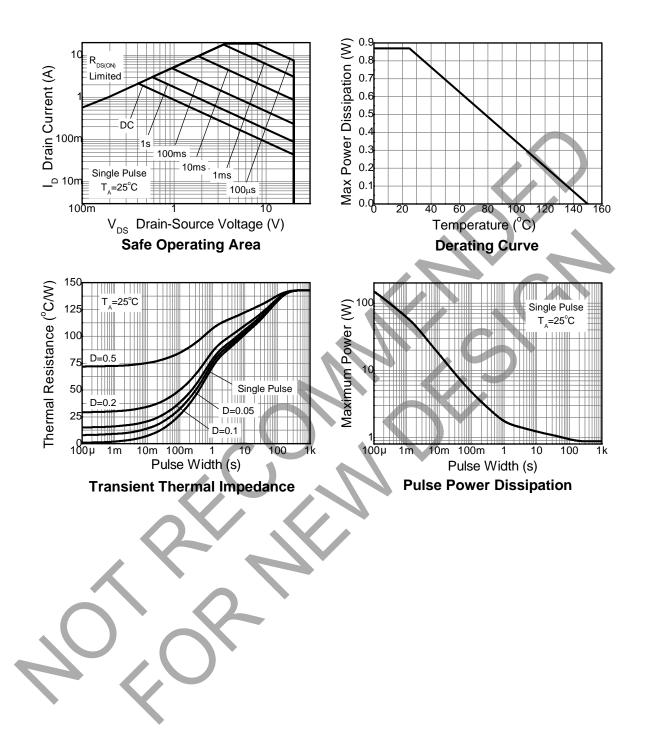
Notes:

For device with one active die.
 Repetitive rating – 25mm x 25mm FR-4 PCB, D = 0.02, pulse width 300us – pulse width limited by maximum junction temperature.
 For a device surface mounted on 25mm x 25mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 For device with two active die running at equal power.
 Thermal resistance from junction to solder-point (at the end of the drain lead).

ZXMD63N02X Document number: DS33500 Rev. 5 - 3



#### **Thermal Characteristics**





Notes:

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

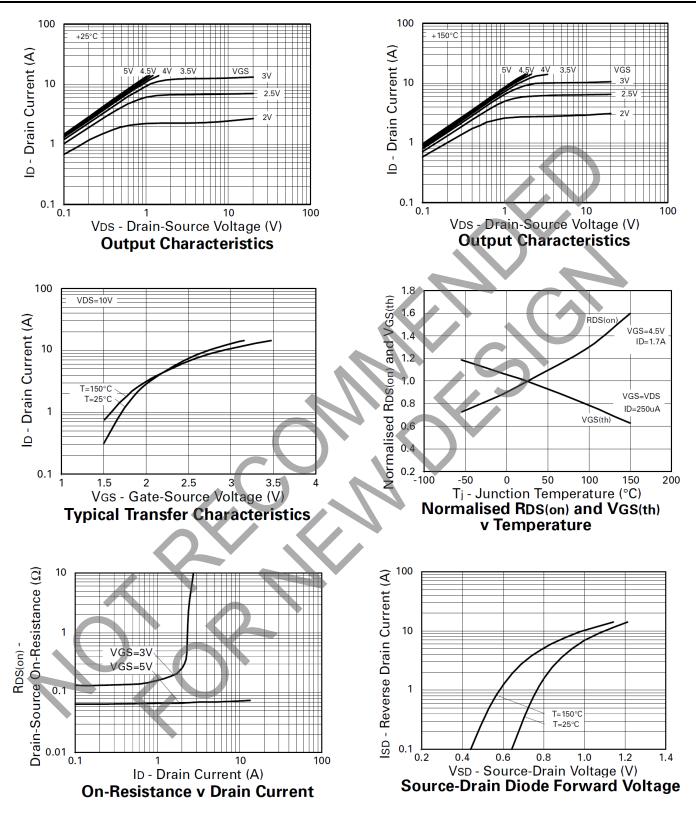
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	20	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	100	nA	$V_{GS} = \pm 12V$ , $V_{DS} = 0V$
ON CHARACTERISTICS						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.7		3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Statia Drain Source On Registence (Note 11)	Р		65	130	mΩ	$V_{GS} = 4.5V, I_D = 1.7A$
Static Drain-Source On-Resistance (Note 11)	R <sub>DS(ON)</sub>	_	90	150	11122	V <sub>GS</sub> = 2.7V, I <sub>D</sub> = 0.85A
Forward Transconductance (Notes 11 & 13)	<b>g</b> fs	2.6	—	—	S	$V_{DS} = 10V, I_D = 0.85A$
Diodes Forward Voltage (Note 11)	V <sub>SD</sub>	_	0.85	0.95	V	TJ = +25°C, I <sub>S</sub> = 1.7A, V <sub>GS</sub> = 0V
DYNAMIC CHARACTERISTICS						
Input Capacitance (Notes 12 & 13)	Ciss	—	350	700		
Output Capacitance (Notes 12 & 13)	Coss	_	120	250	ρF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, If = 1.0MHz
Reverse Transfer Capacitance (Notes 12 & 13)	Crss	_	50	100		1 = 1.00012
Gate Resistance (Notes 12 & 13)	Rg		3.8	7.6	Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge (Notes 12 & 13)	Qg	_	4.5	6		
Gate-Source Charge (Notes 12 & 13)	Q <sub>gs</sub>	—	0.5	0.65	nC	$V_{GS} = 4.5V, V_{DS} = 16V,$
Gate-Drain Charge (Notes 12 & 13)	Q <sub>gd</sub>	—	2	2.5		$I_D = 1.7A$
Reverse Recovery Time (Note 13)	t <sub>RR</sub>	—	15	30	ns	$T_{J} = +25^{\circ}C, I_{F} = 1.7A,$
Reverse Recovery Charge (Note 13)	Q <sub>RR</sub>	—	5.9		nC	di/dt = 100A/µs
Turn-On Delay Time (Notes 12 & 13)	t <sub>D(ON)</sub>		3.4	_		
Turn-On Rise Time (Notes 12 & 13)	t <sub>R</sub>	—	8.1	—	ns	$V_{DD} = 10V, I_D = 1.7A,$
Turn-Off Delay Time (Notes 12 & 13)	t <sub>D(OFF)</sub>	—	13.5	—	ns	$R_G = 6\Omega, R_D = 5.7\Omega$
Turn-Off Fall Time (Notes 12 & 13)	t <sub>F</sub>		9.1	- (		

11. Measured under pulsed conditions. Pulse width  $\leq$  300µs; duty cycle  $\leq$ 2%. 12. Switching characteristics are independent of operating junction temperature. 13. For design aid only, not subject to production testing.

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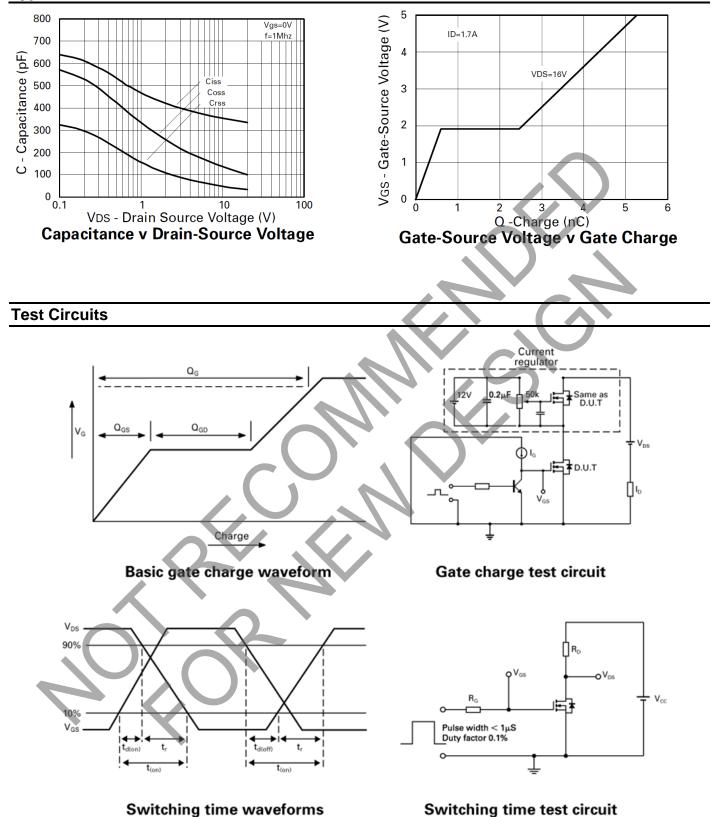


#### **Typical Characteristics**





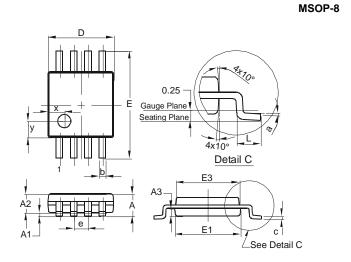
#### Typical Characteristics (Cont.)





#### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dim	Min	Max	Тур	
Α	I	1.10	-	
A1	0.05	0.15	0.10	
A2	0.75	0.95	0.86	
A3	0.29	0.49	0.39	
b	0.22	0.38	0.30	
С	0.08	0.23	0.15	
D	2.90	3.10	3.00	
ш	4.70	5.10	4.90	
E1	2.90	3.10	3.00	
E3	2.85	3.05	2.95	
е	-	-	0.65	•
L	0.40	0.80	0.60	
а	0°	8°	4°	
х	-	-	0.750	
У	-	-	0.750	
All E				

0.650

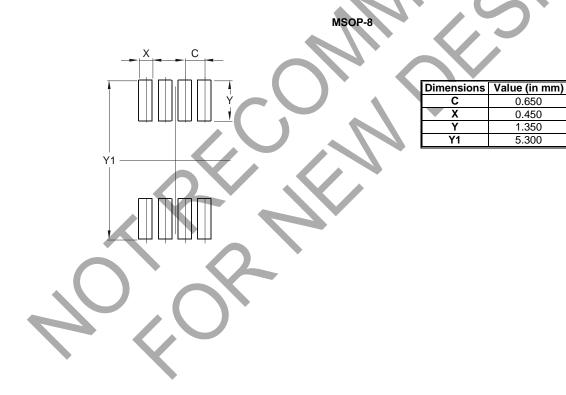
0.450

1.350

5.300

#### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





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